TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

HN1C01FU

Audio Frequency General Purpose Amplifier Applications

• Small package (Dual type)

• High voltage and high current

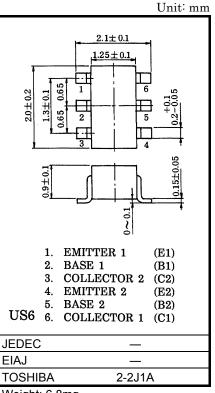
 $: V_{CEO} = 50V, I_{C} = 150mA (max)$

High hfe: hfe = 120~400
Excellent hfe linearity

: h_{FE} ($I_{C} = 0.1 \text{mA}$) / h_{FE} ($I_{C} = 2 \text{mA}$) = 0.95 (typ.)

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

| Characteristic | Symbol | Rating | Unit |
|-----------------------------|------------------|---------|------|
| Collector-base voltage | V _{CBO} | 60 | V |
| Collector-emitter voltage | V _{CEO} | 50 | V |
| Emitter-base voltage | V _{EBO} | 5 | V |
| Collector current | IC | 150 | mA |
| Base current | ΙB | 30 | mA |
| Collector power dissipation | P _C * | 200 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | -55~125 | °C |



Weight: 6.8mg

e: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

* Total rating

Electrical Characteristics (Ta = 25°C) (Q1,Q2 Common)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|------------------------|-----------------|---|-----|------|------|------|
| Collector cut-off current | I _{CBO} | _ | V _{CB} = 60V, I _E = 0 | _ | _ | 0.1 | μΑ |
| Emitter cut-off current | I _{EBO} | _ | V _{EB} = 5V, I _C = 0 | _ | _ | 0.1 | μΑ |
| DC current gain | h _{FE (Note)} | _ | V _{CE} = 6V, I _C = 2mA | 120 | _ | 400 | |
| Collector-emitter saturation voltage | V _{CE (sat)} | _ | I _C = 100mA, I _B = 10mA | - | 0.1 | 0.25 | ٧ |
| Transition frequency | f _T | _ | V _{CE} = 10V, I _C = 1mA | 80 | _ | _ | MHz |
| Collector output capacitance | C _{ob} | _ | V _{CB} = 10V, I _E = 0, f = 1MHz | _ | 2 | 3.5 | pF |

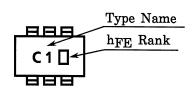
Note: hfe Classification

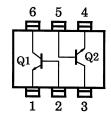
Y (Y): 120~240, GR (G): 200~400

() Marking Symbol

Marking

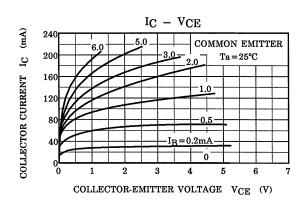
Equivalent Circuit (Top View)

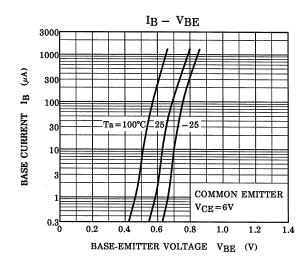


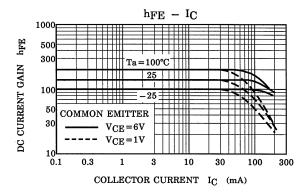


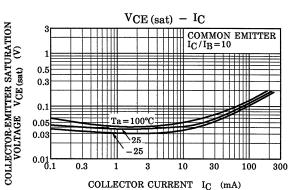
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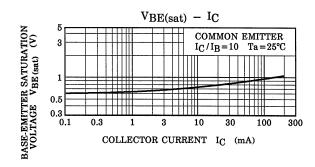
(Q1,Q2 Common)

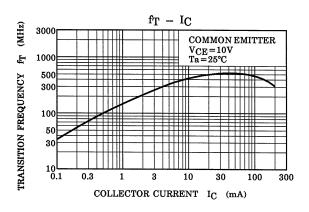


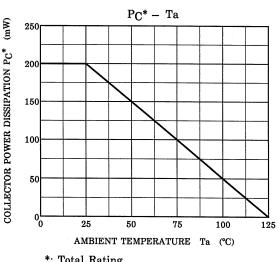












*: Total Rating

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20070701-EN GENERAL

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